TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOSIII)

2SJ668

Relay Drive, DC/DC Converter and Motor Drive Applications

- 4 V gate drive
- Low drain-source ON-resistance: R_{DS} (ON) = 0.12 Ω (typ.)
- High forward transfer admittance: |Y_{fs}| = 5.0 S (typ.)
- Low leakage current: $I_{DSS} = -100 \ \mu A \ (max) \ (V_{DS} = -60 \ V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Character	istic	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	-60	V
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V _{DGR}	-60	V
Gate-source voltage		V _{GSS}	±20	V
Drain current	DC (Note 1)	۱ _D	-5	А
	Pulse(Note 1)	I _{DP}	-20	А
Drain power dissipatio	n (Tc=25°C)	PD	20	W
Single pulse avalanche	e energy (Note 2)	E _{AS}	40.5	mJ
Avalanche current		I _{AR}	-5	А
Repetitive avalanche e	energy (Note 3)	E _{AR}	2	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature ra	ange	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

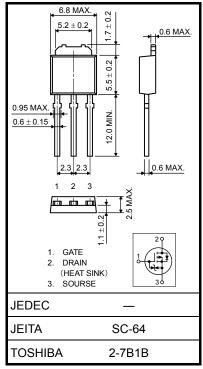
Thermal Characteristics

Characteristic	Symbol	Мах	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	6.25	°C / W	
Thermal resistance, channel to ambient	R _{th (ch−a)}	125	°C / W	

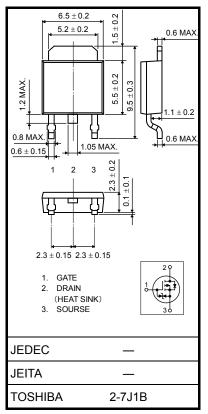
Note 1: Ensure that the channel temperature does not exceed 150°C.

- Note 2: $V_{DD} = -25 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 2.2 mH, $R_G = 25 \Omega$, $I_{AR} = -5 \text{ A}$
- Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.36 g (typ.)



Weight: 0.35 g (typ.)

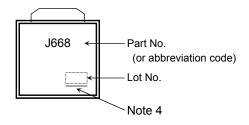
Electrical Characteristics (Ta = 25°C)

Chara	cteristic	Symbol	Test Condition	Min	Тур.	Мах	Unit
Gate leakage current		I _{GSS}	V_{GS} = ±16 V, V_{DS} = 0 V	_		±10	μA
Drain cutoff curr	rent	IDSS	V_{DS} = -60 V, V_{GS} = 0 V	_	_	-100	μA
Drain-source breakdown voltage		V (BR) DSS	I _D = -10 mA, V _{GS} = 0 V	-60		_	V
		V (BR) DSX	I _D = -10 mA, V _{GS} = 20 V	-35		_	V
Gate threshold	voltage	V _{th}	V _{DS} = -10 V, I _D = -1 mA	-0.8	_	-2.0	V
Drain-source ON-resistance		D	V _{GS} = -4 V, I _D = -2.5 A	—	0.16	0.25	Ω
		R _{DS (ON)}	V _{GS} = -10 V, I _D = -2.5 A	_	0.12	0.17	
Forward transfe	r admittance	Y _{fs}	V _{DS} = -10 V, I _D = -2.5 A	2.5	5.0	_	S
Input capacitance Reverse transfer capacitance		C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	700	_	pF
		C _{rss}		_	60	_	
Output capacitance		C _{oss}		_	90	_	
Switching time	Rise time	tr	V_{GS} -10 V C_{GS} -10 V $R_{L} = 12 \Omega$ $V_{DD} \approx -30 V$	_	14	_	
	Turn-on time	t _{on}		_	24	_	ns
	Fall time	t _f		_	14	_	
	Turn-off time	t _{off}	Duty \leq 1%, t _w = 10 µs	_	95	_	
Total gate charge (gate-source plus gate-drain)		Qg		_	15	_	
Gate-source charge		Q _{gs}	V _{DD} ≈ −48 V, V _{GS} = −10 V, I _D = −5 A		11	—	nC
Gate-drain ("Miller") charge		Q _{gd}	1		4	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	-5	А
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	-20	А
Forward voltage (diode)	V _{DSF}	I _{DR} = -5 A, V _{GS} = 0 V	_	_	1.7	V
Reverse recovery time	t _{rr}	I _{DR} = -5 A, V _{GS} = 0 V	_	40	_	ns
Reverse recovery charge	Qrr	dl _{DR} / dt = 50 A/µs	_	32	_	nC

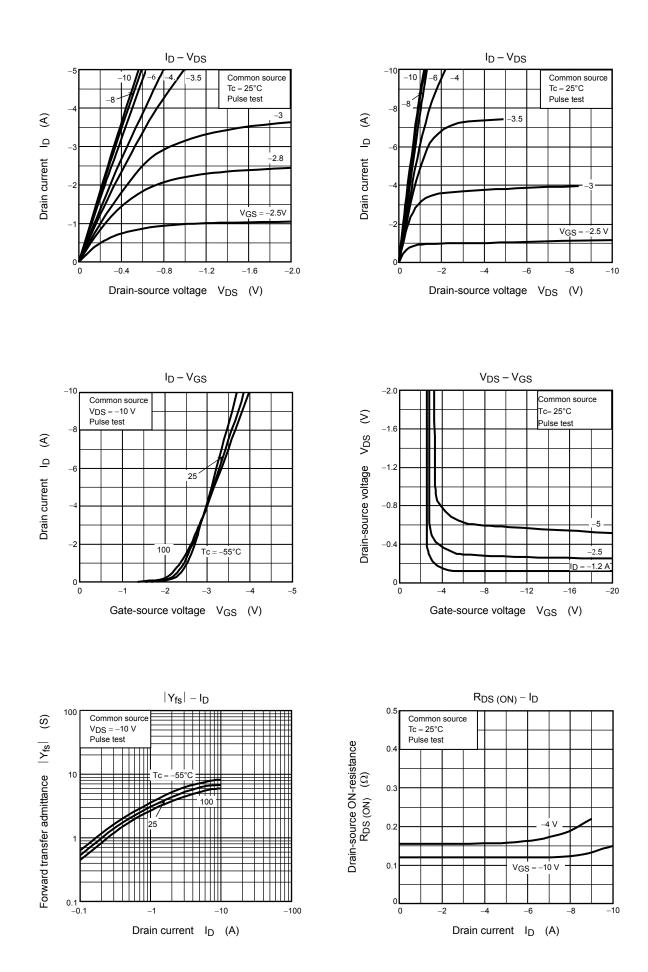
Marking



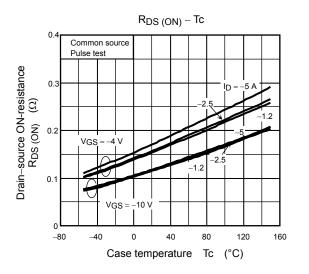
Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

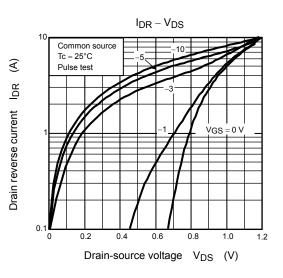
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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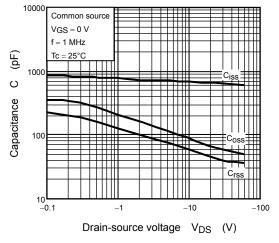


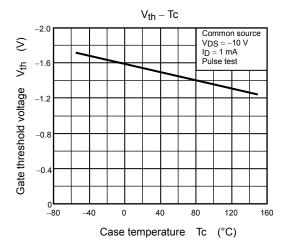
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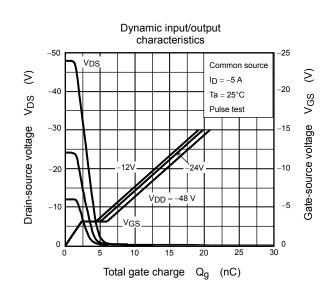


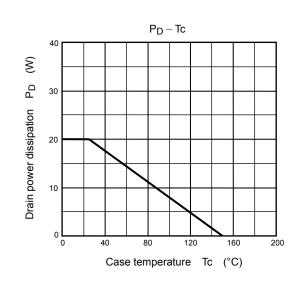


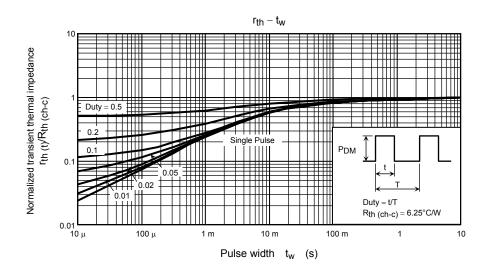
Capacitance – V_{DS}

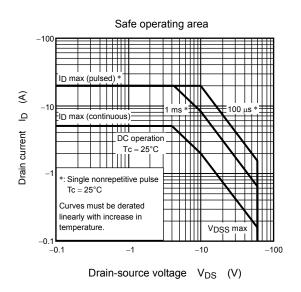


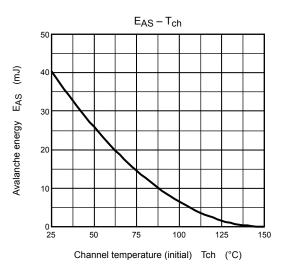


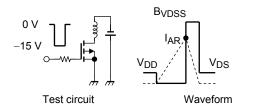


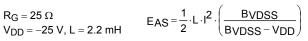












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